

Data Sheet January 2000 File Number 3660.2

8A, 1200V Hyperfast Diode

The RHRP8120 is a hyperfast diodes with soft recovery characteristics ($t_{rr} < 55$ ns). It has half the recovery time of ultrafast diodes and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

Formerly developmental type TA49096.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRP8120	TO-220AC	RHRP8120

NOTE: When ordering, use the entire part number.

Symbol



Features

Hyperfast with Soft Recovery<	55ns
Operating Temperature	5°C
• Reverse Voltage	00V

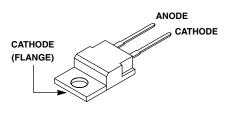
- · Avalanche Energy Rated
- Planar Construction

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC TO-220AC



Absolute Maximum Ratings T_C = 25°C, Unless Otherwise Specified **RHRP8120** UNITS Peak Repetitive Reverse Voltage V_{RRM} 1200 V 1200 V DC Blocking VoltageV_B 1200 8 Α $(T_C = 140^{\circ}C)$ Repetitive Peak Surge CurrentI_{FRM} 16 Α (Square Wave, 20kHz) Nonrepetitive Peak Surge Current I_{FSM} 100 Α (Halfwave, 1 Phase, 60Hz) 75 20 mJ οС -65 to 175

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 8A	-	-	3.2	V
	I _F = 8A, T _C = 150 ^o C	-	-	2.6	V
I _R	V _R = 1200V	-	-	100	μΑ
	V _R = 1200V, T _C = 150 ^o C	-	-	500	μΑ
t _{rr}	$I_F = 1A$, $dI_F/dt = 200A/\mu s$	-	-	55	ns
	$I_F = 8A$, $dI_F/dt = 200A/\mu s$	-	-	70	ns
ta	I _F = 8A, dI _F /dt = 200A/μs	-	30	-	ns
t _b	$I_F = 8A$, $dI_F/dt = 200A/\mu s$	-	20	-	ns
Q _{RR}	I _F = 8A, dI _F /dt = 200A/μs	-	165	-	nC
CJ	$V_{R} = 10V, I_{F} = 0A$	-	25	-	pF
$R_{ heta JC}$		-	-	2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 9), summation of t_{a} + t_{b} .

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse Recovery Charge.

C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse Width.

D = Duty Cycle.

Typical Performance Curves

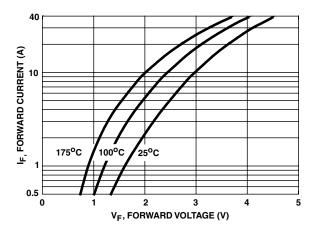


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

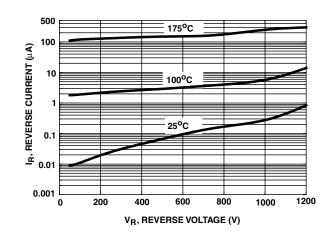


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

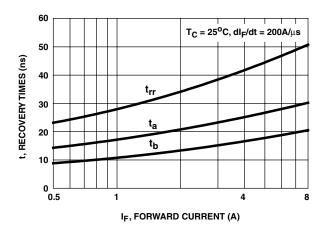


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

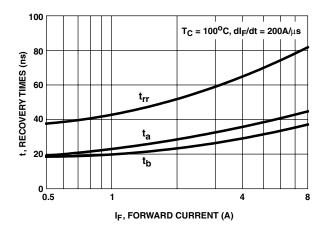


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

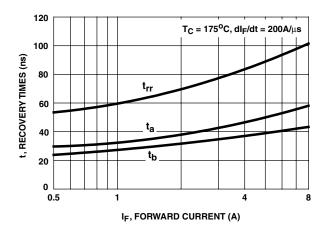


FIGURE 5. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

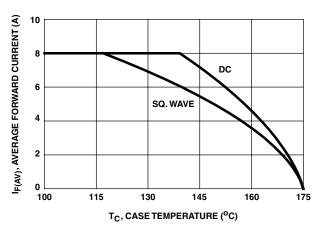


FIGURE 6. CURRENT DERATING CURVE

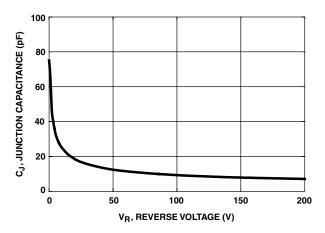


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

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Test Circuits and Waveforms

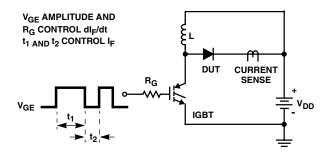


FIGURE 8. t_{rr} TEST CIRCUIT

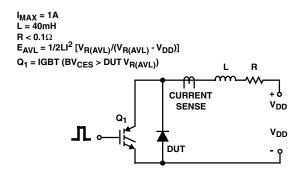


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

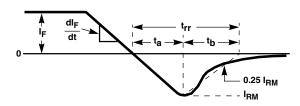


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

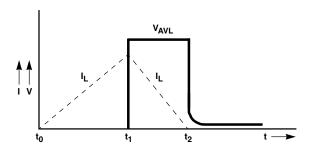


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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DenseTrench™	HiSeC™	QS™	TinyLogic™
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